

Medium Power Transistor (32V, 2A)

2SD1766/2SD1758/2SD1862/2SD1189F/ 2SD1055/2SD1919/2SD1227M

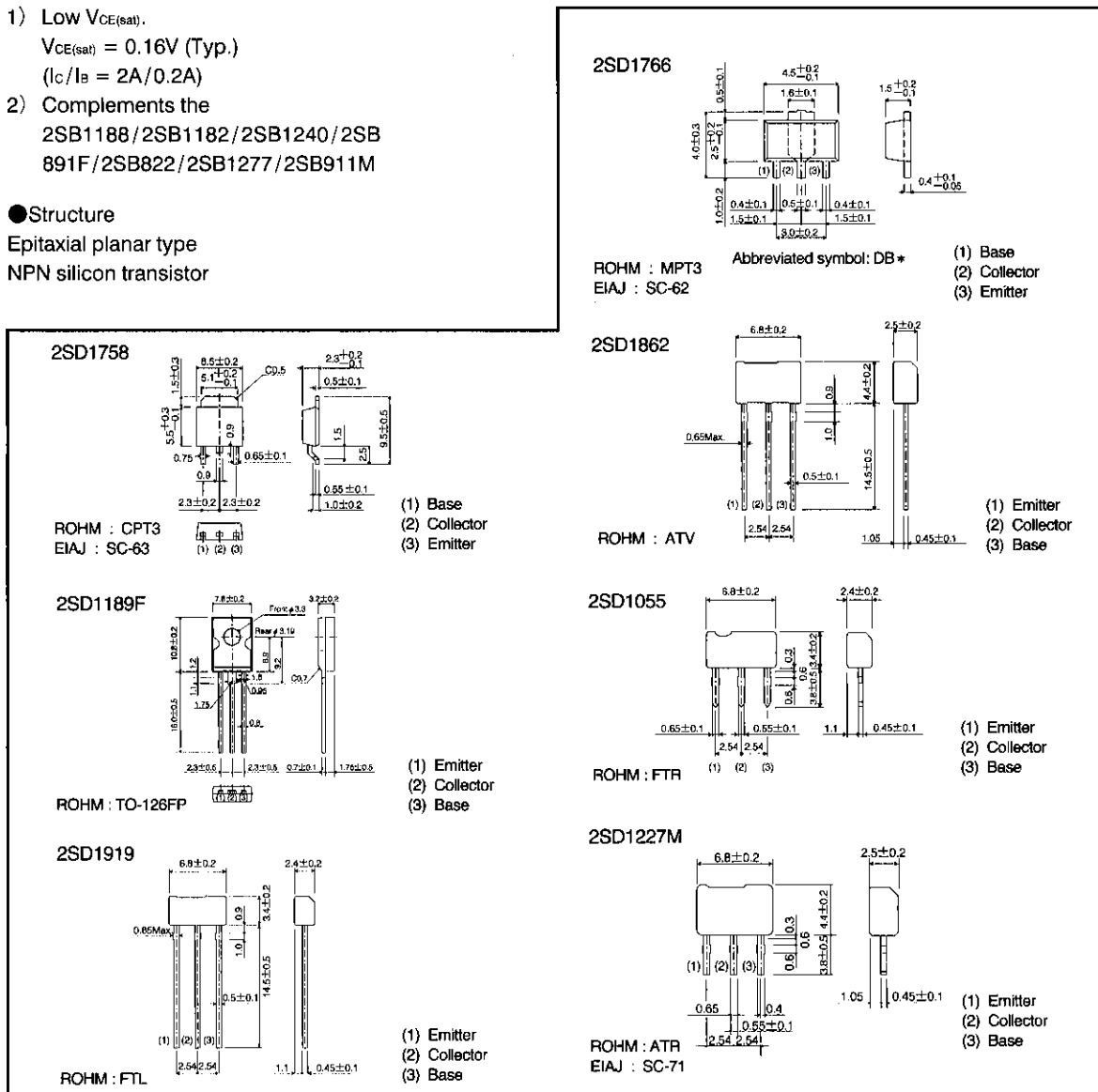
●Features

- 1) LOW $V_{CE(sat)}$,
 $V_{CE(sat)} = 0.16V$ (Typ.)
($I_C/I_B = 2A/0.2A$)
- 2) Complements the
2SB1188/2SB1182/2SB1240/2SB
891F/2SB822/2SB1277/2SB911M

●Structure

Epitaxial planar type
NPN silicon transistor

●External dimensions (Units: mm)



*Denotes hrc

(96-217-B24)

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Collector-base voltage		V _{CB0}	40	V
Collector-emitter voltage		V _{CE0}	32	V
Emitter-base voltage		V _{EB0}	5	V
Collector current		I _c	2	A (DC)
			2.5	A (Pulse) *1
Collector power dissipation	2SD1766	P _c	0.5	W *2
			2	
	2SD1758		10	W (T _c =25°C)
	2SD1862,2SD1227M		1	W *3
			1.2	
2SD1189F	5	W (T _c =25°C)		
2SD1055,2SD1919	0.75	W		
Junction temperature		T _j	150	°C
Storage temperature		T _{stg}	-55~150	°C

*1 Single pulse P_w=20ms

*2 On 40 x 40 x 0.7 mm ceramic board.

*3 Printed circuit board: 1.7 mm thick, collector copper plating 1 cm² or more.

● Electrical characteristics (Ta = 25°C)

Parameter		Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage		BV _{CB0}	40	—	—	V	I _c =50 μA
Collector-emitter breakdown voltage		BV _{CE0}	32	—	—	V	I _c =1mA
Emitter-base breakdown voltage		BV _{EB0}	5	—	—	V	I _E =50 μA
Collector cutoff current		I _{CB0}	—	—	1	μA	V _{CB} =20V
Emitter cutoff current		I _{EB0}	—	—	1	μA	V _{EB} =4V
DC current transfer ratio	2SD1766,2SD1758,2SD1189F	h _{FE}	82	—	390	—	V _{CE} =3V, I _c =0.5A * *
	2SD1862		120	—	390		
	2SD1055		180	—	390		
	2SD1919,2SD1227M		120	—	270		
Collector-emitter saturation voltage		V _{CE(sat)}	—	0.5	0.8	V	I _c /I _B =2A/0.2A *
Transition frequency		f _T	—	100	—	MHz	V _{CE} =5V, I _E =-50mA, f=100MHz *
Output capacitance		C _{ob}	—	30	—	pF	V _{CB} =10V, I _E =0A, f=1MHz

* Measured using pulse current.

●Packaging specifications and h_{FE}

Type	h_{FE}	Package Symbol Basic ordering unit (pieces)	Taping			Bulk		
			T100	TL	TV2	—	—	TL2
			1000	2500	2500	1000	2000	2500
2SD1766	PQR	○	—	—	—	—	—	
2SD1758	PQR	—	○	—	—	—	—	
2SD1862	QR	—	—	○	—	—	—	
2SD1189F	PQR	—	—	—	○	—	—	
2SD1055	R	—	—	—	—	○	—	
2SD1919	Q	—	—	—	—	—	○	
2SD1227M	Q	—	—	—	—	○	—	

h_{FE} values are classified as follows :

Item	P	Q	R
h_{FE}	82~180	120~270	180~390

●Electrical characteristic curves

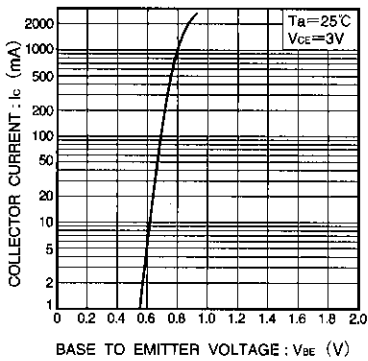


Fig.1 Grounded emitter propagation characteristics

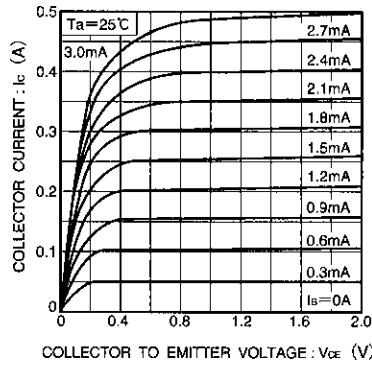


Fig.2 Grounded emitter output characteristics

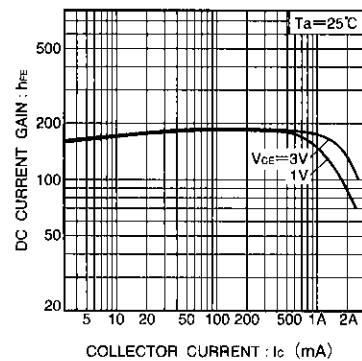


Fig.3 DC current gain vs. collector current

●Electrical characteristic curves

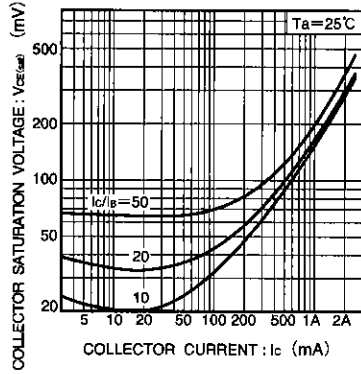


Fig.4 Collector-emitter saturation voltage vs. collector current

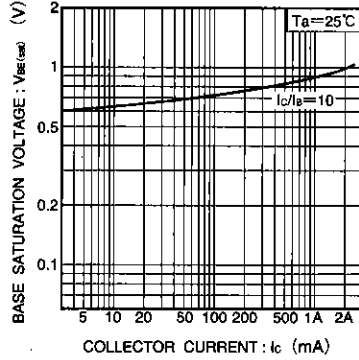


Fig.5 Collector-emitter saturation voltage vs. collector current

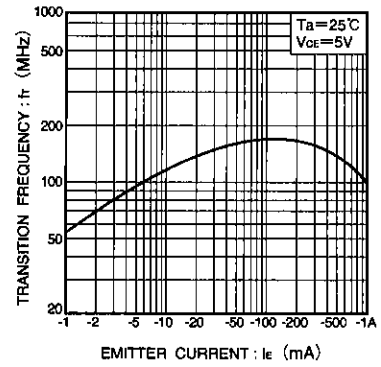


Fig.6 Transition frequency vs. emitter current

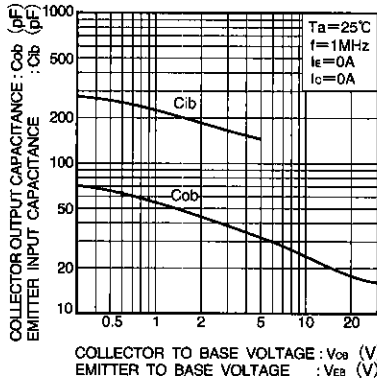


Fig.7 Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage

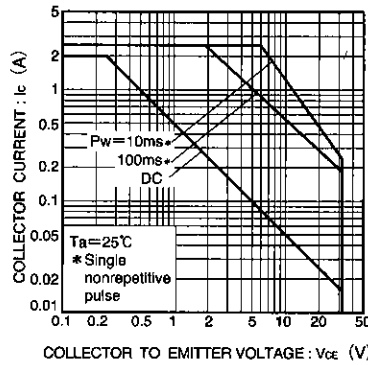


Fig.8 Safe operating area (2SD1766)

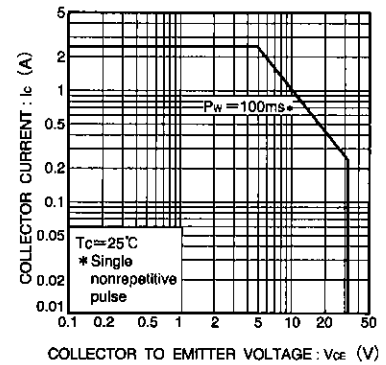


Fig.9 Safe operating area (2SD1758)

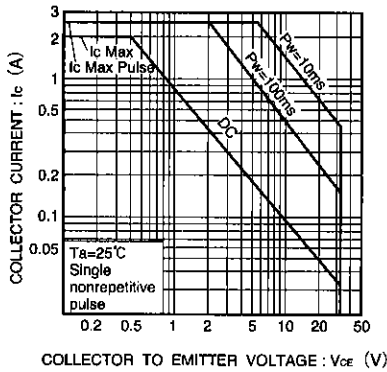


Fig.10 Safe operating area (2SD1862, 2SD1227M)

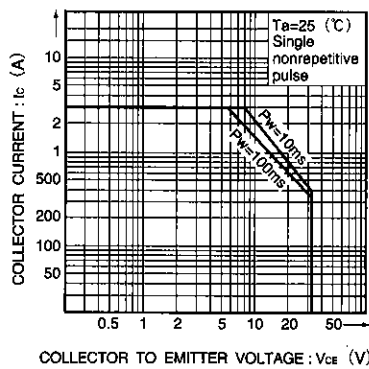


Fig.11 Safe operating area (2SD1189F)

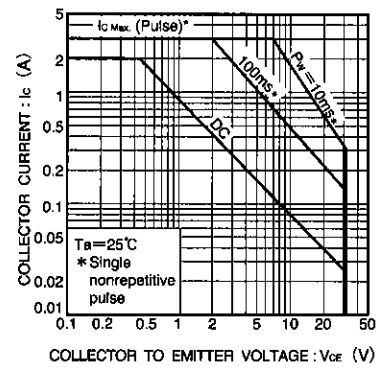


Fig.12 Safe operating area (2SD1055, 2SD1919)

Bipolar transistors

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